

# Asymmetric magnetic proximity interactions in van der Waals heterostructures

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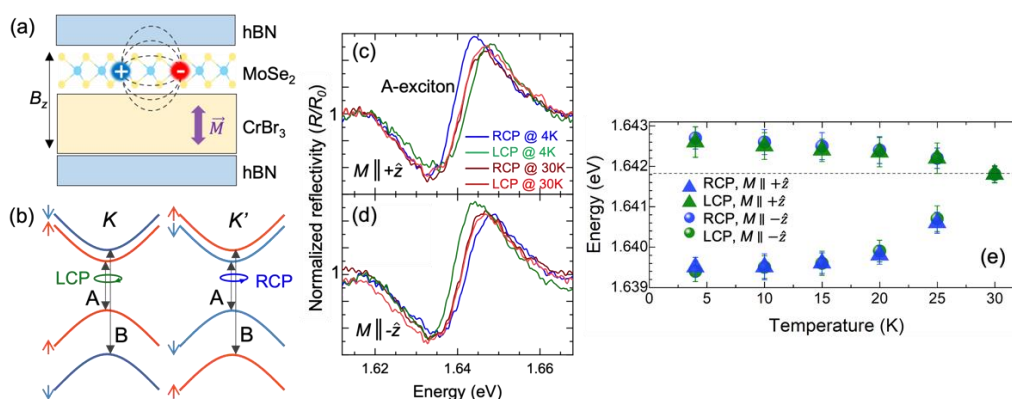
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Magnetic proximity interactions (MPIs) between atomically thin semiconductors and two-dimensional magnets provide a means to manipulate spin and valley degrees of freedom in non-magnetic monolayers, without using applied magnetic fields. In such van der Waals heterostructures, MPIs originate in the nanometre-scale coupling between spin-dependent electronic wavefunctions in the two materials, and typically their overall effect is regarded as an effective magnetic field acting on the semiconductor monolayer. Here we demonstrate that MPIs in MoSe<sub>2</sub>/CrBr<sub>3</sub> van der Waals heterostructures can in fact be markedly asymmetric [1]. Valley-resolved reflection spectroscopy reveals strikingly different energy shifts in the K and K' valleys of the MoSe<sub>2</sub> due to ferromagnetism in the CrBr<sub>3</sub> layer. Density functional calculations indicate that valley-asymmetric MPIs depend sensitively on the spin-dependent hybridization of overlapping bands and as such are likely a general feature of hybrid van der Waals structures.

## References

[1] J. Choi, C. Lane, J.-X. Zhu, S. A. Crooker, *Nature Materials*, 22 (2023), 305-310

## Figures



**Figure 1:** (a) Layer schematic of hBN/MoSe<sub>2</sub>/CrBr<sub>3</sub>/hBN heterostructure. The red and blue spheres depict and electron and hole pair in the MoSe<sub>2</sub>, forming an exciton. (b) Band diagram depicting the relevant optical transitions of A and B excitons in MoSe<sub>2</sub>. (c, d) Comparison of the MPI-induced shift of the MoSe<sub>2</sub> A exciton in the K and K' valleys at T=4 K, as measured by the normalized reflection spectra, R/R<sub>0</sub>, of left circularly polarized (LCP) and right circularly polarized (RCP) light (green and blue traces, respectively). The CrBr<sub>3</sub> magnetization M is oriented along +z or -z. Red and orange traces show reference spectra acquired at 30 K (above T<sub>C</sub>), where the CrBr<sub>3</sub> is unmagnetized. (e) Temperature dependence of the MPI-induced valley shifts of the A exciton, for both circular polarizations and for both ±z CrBr<sub>3</sub> magnetizations. The horizontal line indicates the exciton resonance energy at 30 K when the CrBr<sub>3</sub> is not magnetic.